

Shankar Swaminathan

List of Publications by Year in descending order

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Version: 2024-02-01

5
papers

174
citations

1937685

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2053705

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all docs

5
docs citations

5
times ranked

289
citing authors

#	ARTICLE	IF	CITATIONS
1	Bilayer metal oxide gate insulators for scaled Ge-channel metal-oxide-semiconductor devices. Applied Physics Letters, 2010, 96, .	3.3	64
2	Ultrathin ALD-Al ₂ O ₃ layers for Ge(001) gate stacks: Local composition evolution and dielectric properties. Journal of Applied Physics, 2011, 110, .	2.5	56
3	Oxidant prepulsing of Ge (100) prior to atomic layer deposition of Al ₂ O ₃ : <i>in situ</i> surface characterization. Applied Physics Letters, 2009, 95, .	3.3	36
4	Titania/Alumina Bilayer Gate Dielectrics for Ge MOS Devices: Frequency- and Temperature-Dependent Electrical Characteristics. Electrochemical and Solid-State Letters, 2010, 13, G79.	2.2	13
5	(Invited) In Situ XPS in Atomic Layer Deposition of Oxides on Ge (100). ECS Transactions, 2010, 33, 455-462.	0.5	5